

Symbol

Advance Technical Information

GenX3[™] 1200V IGBTs

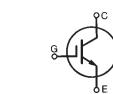
IXGK120N120B3 IXGX120N120B3

$$V_{CES} = 1200V$$

 $I_{C90} = 120A$
 $V_{CE(sat)} \le 3.0V$

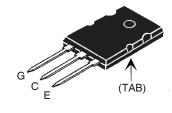
High Speed Low Vsat PT IGBTs for 3-20 kHz Switching

Test Conditions

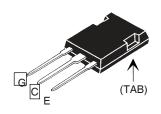


Maximum Ratings

TO-264 (IXGK)



PLUS 247[™] (IXGX)



G = Gate E = EmitterC = Collector TAB = Collector

Features

- Optimized for Low Conduction and Switching Losses
- Square RBSOA
- International Standard Packages

Advantages

- High Power Density
- Low Gate Drive Requirement

Applications

- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

Symbol		waximum nating5			
V _{ces}	$T_{J} = 25^{\circ}C$ to $150^{\circ}C$	1200	V		
V _{CGR}	$T_{_J}$ = 25°C to 150°C, $R_{_{GE}}$ = 1M Ω	1200	V		
V _{ges}	Continuous	±20	V		
V _{gem}	Transient	±30	V		
I	$T_{c} = 25^{\circ}C$ (Chip Capability)	200	A		
I _{C90}	$T_{c} = 90^{\circ}C$	120	A		
I _{LRMS}	Terminal Current Limit	120	A		
I _{CM}	$T_c = 25^{\circ}C$, 1ms	370	A		
SSOA	$V_{ge} = 15V, T_{vj} = 125^{\circ}C, R_{g} = 2\Omega$	I _{CM} = 240	A		
(RBSOA)	Clamped Inductive Load	$V_{\text{CES}} \le 1200$	V		
P _c	$T_c = 25^{\circ}C$	830	W		
Tj		-55 +150	°C		
T _{JM}		150	°C		
T _{stg}		-55 +150	°C		
T	Maximum Lead Temperature for Soldering	300	°C		
	1.6 mm (0.062 in.) from Case for 10	260	°C		
M _d	Mounting Torque (IXGK)	1.13/10	Nm/lb.in.		
F _c	Mounting Force (IXGX)	20120/4.527	N/lb.		
Weight	TO-264	10	g		
	PLUS247	6	g		

Symbol	Symbol Test Conditions Charac					
$(T_{J} = 25^{\circ}C, 1)$	Unless Otherwise Specified)	Min.	Тур.	Max.		
BV _{CES}	$I_{c} = 250 \mu A, V_{ce} = 0V$	1200		V		
V _{GE(th)}	I_{c} = 1mA, $V_{ce} = V_{ge}$	3.0		5.0 V		
I _{CES}	$V_{CE} = V_{CES} V_{GE} = 0V$			50 µA		
	·	$T_J = 125^{\circ}C$		5 mA		
I _{ges}	$V_{CE} = 0V, V_{GE} = \pm 20V$			±400 nA		
V _{CE(sat)}	$I_{c} = 100A, V_{ge} = 15V, Note$	e 1	2.4	3.0 V		

	XYS					
Symbol (T _J = 25°C	Test Conditions , Unless Otherwise Specified)	Char Min.	naracteristic Values n. Typ. Max.			
9 _{fs}	$I_{c} = 60A, V_{ce} = 10V, Note 1$	40	70	S		
C _{ies})			9700	pF		
C _{oes}	$V_{CE} = 25V, V_{GE} = 0V, f = 1 MHz$		670	pF		
C _{res}			255	pF		
Q _{g(on)}			470	nC		
Q _{ge} }	$I_{c} = I_{c90}, V_{ge} = 15V, V_{ce} = 0.5 \bullet V_{ces}$		67	nC		
Q _{gc})			190	nC		
t _{d(on)}			36	ns		
t _{ri}	Inductive load, $T_J = 25^{\circ}C$		88	ns		
E _{on}	$I_{c} = 100A, V_{ge} = 15V$		5.5	mJ		
t _{d(off)}	$V_{ce} = 600V, R_{g} = 2\Omega$		275	ns		
t _{fi}	Note 2		145	ns		
E _{off} /			5.8	mJ		
t _{d(on)}			34	ns		
t _{ri}	Inductive load, T _J = 125°C		88	ns		
E _{on}	$I_{c} = 100A, V_{GE} = 15V$		6.1	mJ		
t _{d(off)}	$V_{ce} = 600V, R_{g} = 2\Omega$		315	ns		
t _{fi}	Note 2		570	ns		
E /			10.3	ml		

IXGK120N120B3 IXGX120N120B3

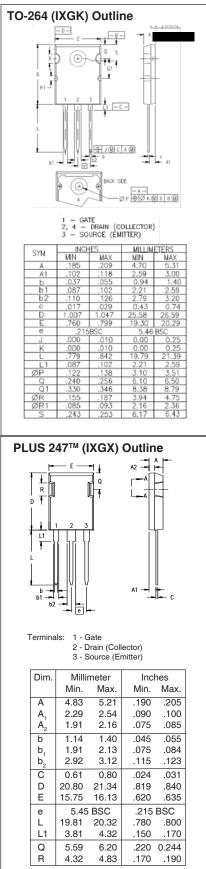
mJ

°C/W

0.15 °C/W

10.3

0.15



Note

 $\mathbf{E}_{_{\mathrm{off}}}$

R_{thJC}

R_{thCK}

- 1. Pulse Test, t \leq 300µs, Duty Cycle, d \leq 2%.
- 2. Switching Times may Increase for V_{ce} (Clamp) > 0.8 V_{ces} , Higher T_j or Increased R_g .

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the	Bight to C	hange Limits.	Test Conditions	and Dimensions.
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IXYS MOSFETs and IGBTs are covered	4 995 500	4 021 044	E 040 061	5.237.481	6 160 665	6.404.065 B1	6 602 244	6 707 595	7.005.734 B2	7 157 00000
INTS MOSPETS and IGDTS are covered	4,035,592	4,931,044	5,049,901	5,237,401	0,102,005	0,404,005 DT	0,003,344	0,727,505	7,005,754 BZ	1,107,0002
by one or more of the following U.S. patents	: 4,850,072	5,017,508	5,063,307	5,381,025	6,259,123 B1	6,534,343	6,710,405 B2	6,759,692	7,063,975 B2	
	4,881,106	5,034,796	5,187,117	5,486,715	6,306,728 B1	6,583,505	6,710,463	6,771,478 B2	2 7,071,537	



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